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- (54)Method for producing ceramic diaphragm structure
- A method for producing a ceramic diaphragm structure, includes: superposing a thin ceramic green sheet having at least one layer on a ceramic green substrate having at least one window portion and at least one layer so as to cover the window portion to obtain a unitary laminate; and firing the unitary laminate so that a diaphragm portion has a protrusion toward a side opposite to the window portion; wherein the ceramic green substrate and the ceramic green sheet satisfy the formulae:
 - S(substrate) S(sheet) ≥ -0.08 {T₇₀(substrate) T₇₀(sheet)} 1
 - $0 \le T_{70}(\text{substrate}) \cdot T_{70}(\text{sheet}) \le 300$

and

3) S(substrate) - S(sheet) ≤ 20

(S(substrate), and S(sheet) denote shrinkage rates (%) of the ceramic green substrate and the ceramic green sheet, respectively. T70(substrate) and T70(sheet) denote mid-sintering temperatures (°C) of the ceramic green substrate and the ceramic green sheet, respectively.) and an average sintering temperature difference, shown by the formula:

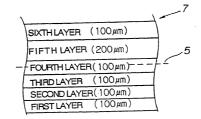
> ΣΤ₇₀(substrate), the x dx 4)

(N denotes the number of layers constituting the ceramic green substrate. T₇₀(substrate)_n denotes a mid-sintering temperature (°C) of a layer positioned in number n place from the bottom of the laminate in the ceramic green substrate having the ceramic green sheet thereon. t_n and t_{n+1} denote distances from a lower and an upper surfaces, respectively, of the layer positioned in numbers n place to a neutral line of the substrate after firing the unitary laminate, with putting - for a surface under the neutral line and + for a surface over the neutral line.) of the ceramic green substrate is larger than 0.

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FIG. 3

FIG. 4



Description

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Background of the Invention and Related Art Statement

The present invention relates to a method for producing a ceramic diaphragm structure which is used as a constitutional member of various kinds of sensors, piezoelectric/electrostrictive actuators, or the like.

A ceramic diaphragm structure has a structure in which a thin and flexible diaphragm plate is superposed on a substrate having at least one window portion so as to cover the window portion and to work as a diaphragm. Such a substrate diaphragm structure is used for various kinds of sensors by constituting so that a diaphragm portion detects ceramic diaphragm structure is used for various kinds of sensors by constituting so that a diaphragm portion detects a bending displacement originated from a subject to be measured by an adequate means, or used as a constituting member of a piezoelectric/electrostrictive actuator by giving a pressure to the pressure room formed inside the actuator by deformation of the diaphragm portion.

A ceramic diaphragm structure is produced by unitarily superposing a thin ceramic green sheet (hereinafter referred to as a green sheet) on a ceramic green substrate (hereinafter referred to as a green sheet) on a ceramic green substrate (hereinafter referred to as a green sheet) to obtain a laminate, and subsequently firing the laminate. After firing, a green substrate becomes a substrate, and a green sheet becomes a diaphragm plate. In recent years there has been used a ceramic diaphragm structure 3 which has a diaphragm portion 1 having a protrudent shape toward the side opposite to a window portion 8 of a substrate 2 as substrate 2 as substrate 2 as substrate 2 as a substra

When a ceramic diaphragm structure having a protrudent shape is produced, there are used materials for a green substrate and a green sheet, i.e., materials within a range shown by a stanting line in Fig. 2, which satisfies the following formulae 1), 2), and 3).

S(substrate)-S(sheet)≥-0.08(T₇₀(substrate)-T₇₀(sheet)}-1

0≤T₇₀(substrate)-T₇₀(sheet)≤300

3) S(substrate)-S(sheet)≤20

(S(substrate) and S(sheet) denote shrinkage rates (%) of the green substrate and the green sheet, respectively. T₇₀ (substrate) and T₇₀(sheet) denote mid-sintering temperatures of the green substrate and the green sheet.) Japanese Patent Laid-Open 8-51236 discloses that by using such a material, a protrusion can be made in a green

Japanese Patent Laid-Open 8-51236 discloses that by using sour a misclose is post-to-misclose and a state of the like. That is, a sheet toward the side opposite to a window portion in a substrate during firing without any crack or the like. That is, a sheet toward the side opposite to a window portion in a substrate and mid-sintering temperature between a thin ceramic portion can be formed by setting differences in shrinkage rate and mid-sintering temperature between a thin ceramic portion can be formed by setting differences in shrinkage rate and mid-sintering temperature between a thin ceramic portion can be formed by setting differences in shrinkage rate and mid-sintering temperature between a thin ceramic portion and the sintering temperature between a shrinkage rate and mid-sintering temperature between a thin ceramic portion in a substrate and mid-sintering temperature between a thin ceramic portion in a substrate and mid-sintering temperature between a thin ceramic portion can be formed by setting differences in shrinkage rate and mid-sintering temperature between a thin ceramic portion can be formed by setting differences in shrinkage rate and mid-sintering temperature between a thin ceramic portion in the sintering temperature between a shrinkage rate and mid-sintering temperature between a thin ceramic portion in the sintering temperature by the sintering temperature between a shrinkage rate and mid-sintering temperature between a shrinkage rate and mid-sinterin

Incidentally, a shrinkage rate (%) means a shrinkage rate (%) of a green substrate and a green sheet independently fired at the same temperature as firing a laminate in a direction of a surface, and the shrinkage rate (%) is shown by (flength before firing) - length after firing/length before firing) x 100(%). A direction of a surface is not the direction of thickness, and it means a predetermined direction on the surface where a green substrate or a green sheet is model hickness, and it means a predetermined direction on the surface where a green substrate or a green sheet is model. A mid-sintering temperature means a firing temperature at which a shrinkage reaches 70% of the adorementioned shrinkage rate, gleubstrate) and S(sheet) in a firing step, and a mid-sintering temperature is an barometer showing a shirinkage reache.

However, the method disclosed in Japanese Patent Laid-Open 6-51239 is on the supposition that a shrinkage rate and a mid-sintering temperature of a green substrate are even from a portion near a green sheet to a portion apart from the green sheet. In this method, a diaphragm structure has a large werkness, and a warpage is caused wholly in corrain plate including diaphragm structures. As shown in Fig. 5 and Fig. 7, a ceramic diaphragm structure 3 is constituted of a substrate 2 and a diaphragm plate 12. Apturality of the corrain claphragm structures oscittutes a ceramic plate 15. It is difficult to reform the alorementioned warpage and warviness even if the ceramic plate 15 is too flictult to reform the alorementioned warpage and warviness so diaphragm structures a substrate damage(s). When a warpage or a warviness is left as it is, a dimensional prociseness of a diaphragm structure deteriorates, and therefore, a preciseness of printing of a pattern on a diaphragm plate deteriorates, and or a variance of a thickness of a film formed on the diaphragm plate is generated. Accordingly, when such a diaphragm structure is used for a sensor, the sensor has a variance of detection preciseness; and when it is used for a piezoelectric/electros-

trictive actuator, the actuator has deterioration or variance of displacement.

Accordingly, the present invention aims to provide a method for producing a ceramic diaphragm structure, which can form a diaphragm portion having a protrusion toward the side opposite to a window portion of a substrate and which can advantageously minimize a waviness of a diaphragm structure and/or a warpage of a ceramic plate including diaphragm structures.

Summary of the Invention

According to the present invention, there is provided a method for producing a ceramic diaphragm structure, comprising:

superposing a thin ceramic green sheet having at least one layer on a ceramic green substrate having at least one window portion and at least one layer so as to cover the window portion to obtain a unitary laminate; and

firing the unitary laminate so that a diaphragm portion has a protrusion toward a side opposite to the window portion;

wherein the ceramic green substrate and the ceramic green sheet satisfy the formulae:

2)
$$0 \le T_{70}$$
(substrate) - T_{70} (sheet) ≤ 300

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(S(substrate), and S(sheet) denote shrinkage rates (%) of the ceramic green substrate and the ceramic green sheet, respectively. T₂₀(substrate) and T₂₀(sheet) denote mid-sintering temperatures (*C) of the ceramic green substrate and the ceramic green sheet, respectively). And an average sintering temperature difference, shown by the formula

4)
$$\sum_{r=1}^{K} T_{70} (\text{substrate})_n \int_{r}^{t_{n+1}} \times dx$$

(N denotes the number of layers constituting the ceramic green substrate. T₇₀(substrate)_n denotes a mid-sintering temperature (°C) of a layer positioned in number n place from the bottom of the laminate in the ceramic green substrate having the ceramic green sheet thereon. L₁ and t_{1n}, a fenote distances from a lower and an upper surfaces, respectively, of the layer positioned in numbers n place to a neutral line of the substrate after firing the unitary laminate, with putting - lor a surface under the neutral line and + for a surface over the neutral line.) of the ceramic green substrate is larger than 0.

According to the present invention, there is also provided a method for producing a ceramic diaphragm structure, comprising:

superposing a thin ceramic green sheet having at least one layer on a ceramic green substrate having at least one window portion and at least one layer so as to cover the window portion to obtain a unitary laminate; and

firing the unitary laminate so that a diaphragm portion has a protrusion toward a side opposite to the window portion;

wherein the ceramic green substrate and the ceramic green sheet satisfy the formulae;

0 ≤ T₇₀(substrate) - T₇₀(sheet) ≤ 300

and

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S(substrate) - S(sheet) ≤ 20

(S(substrate), and S(sheet) denote shrinkage rates (%) of the ceramic green substrate and the ceramic green sheet, respectively. T₇₀(substrate) and T₇₀(sheet) denote mid-sintering temperatures (°C) of the ceramic green substrate and the ceramic green sheet, respectively.) and an average shrinkage-rate difference, shown by the formula 5)

(N denotes the number of layers constituting the ceramic green substrate. S(substrate) n denotes a shrinkage rate (%) of a layer positioned in number n place from the bottom of the laminate in the ceramic green substrate having the ceramic green sheet thereon. 1, and 1,n-1 denote distances from a lower and an upper surfaces, respectively, of the layer positioned in numbers n place to a neutral line of the substrate after firing the unitary laminate, with putting for a surface under the neutral line and + for a surface over the neutral line.) of the ceramic green substrate is larger than 0.

Preferably, a mid-sintering temperature (°C) obtained by formula 6)

6)
$$\sum_{n=1}^{N} [A_n \times T_{70}(substrate)_n]/A$$

(M denotes the number of layers positioned under the neutral line among the layers constituting a substrate after firing the unitary laminate. A_n denotes a thickness of a layer positioned in number n place from the bottom of the ceramic substrate after firing the unitary laminate. However, concerning the layer positioned innumber M, A₀, denotes a distance from the lower surface of the layer to the neutral line. Tr₀(Substrate), denotes a mid-sintering temperature (°C) of a layer positioned in number n place from the bottom of the laminate in the ceramic green substrate having the ceramic green sheet thereon. A denotes a distance from the lower surface of the lowest layer to the neutral line of the substrate after firing the unitary laminate.) is larger than a mid-sintering temperature (°C) of the ceramic green sheet, the mid-sintering temperature (°C) being obtained by the formula 7)

7)
$$\sum_{n=0}^{\infty} [B_n \times T_{70}(\text{sheet})_n]/B$$

(L denotes the number of layers constituting the ceramic green sheet. T₇₀(sheet)_A denotes a mid-sintering temperature (°C) of a layer positioned in number n place from the bottom of the laminate constituting the ceramic green sheet when the ceramic green sheet is positioned in the upside of the ceramic green substrate. B_A denotes a thickness of a layer positioned in number n place from the bottom of the layers constituting a diaphragm plate after firing the unitary laminate.

B denotes a thickness of the diaphragm plate.)
The ceramic green sheet is preferably made of a partially stabilized zirconia, completely stabilized zirconia, alumina or a mixture thereof, or a raw material which become one of the aforementioned materials after being fired, any of them having an average particle diameter of 0.05 - 1.0 µm.

Brief Description of the Drawings

- Fig. 1 is a cross sectional view showing an embodiment of a ceramic diaphragm structure having a diaphragm
- portion having a prorudent shape.

 Fig. 2 is a graph showing a range of values of shrinkage rates and mid-sintering temperatures of a green substrate
 Fig. 2 is a graph showing a range of values of shrinkage rates and mid-sintering temperatures of a green substrate
 Fig. 2 is a graph showing a range of values of shrinkage rates and mid-sintering temperatures of a green substrate.
 - Fig. 3 is a cross sectional view showing another example of a ceramic diaphragm structure having a diaphragm portion having a protrudent shape.

Fig. 4 is a partial, cross sectional view showing an embodiment of a ceramic substrate after firing the unitary laminate having a plurality of layers.

Fig. 5 is a cross sectional view showing still another example of a ceramic diaphragm structure having a diaphragm portion having a protrudent shape.

Fig. 6 is a cross sectional view showing still another example of a ceramic diaphragm portion having a protrudent shape.

Fig. 7 is a perspective view showing a ceramic plate having a plurality of ceramic diaphragm structures.

Detailed Description of the Preferred Embodiments

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In the present invention, a ceramic diaphragm structure is produced by using a green substrate and a green sheet, both having shrinkage rates and mid-sintering temperatures satisfying the following formulae 1), 2), and 3):

2)
$$0 \le T_{70}(\text{substrate}) - T_{70}(\text{sheet}) \le 300$$

(Symbols in the formulae mean as described above.) Further, in the substrate a difference in average sintering temperature shown by the formula 4) should be larger than 0. or a difference in average shrinkage rate shown by the formula 5) should be larger than 0.

4)
$$\sum_{n=1}^{N} T_{70}(substrate)_n \int_{tn}^{tn+1} x dx$$

5)
$$\sum_{n=1}^{\infty} S(substrate)_n \int_{tn}^{tn+1} \times dx$$

In the formula 4), N denotes a number of layers constituting a green substrate. T₇₀(substrate), denotes mid-sintering temperature (*C) of a layer positioned in number n place from the bottom of the laminate in the ceramic green substrate having the ceramic green sheet thereon as shown in Fig. 3. I, and I₁₊₁, denote distances from a lower and supper surfaces, respectively, of the layer positioned in numbers n place to a neutral line 5 of the substrate, with putting -for a surface under the neutral line and + for a surface over the neutral line. The neutral line 5 is a line formed by connecting middle points to one another between the lowers urface of the lowest layer 4 and the upper surface of the layer 6 positioned in number N place after firing the unitary laminate. In the formula 5), S(substrate), denote a shrinkage rate (%) of a layer positioned in number n place from the lowest layer of the substrate having a green sheet thereon.

Incidentally, S(substrate) in the formula 1) can be calculated by the following formula 8):

8)
$$S(substrate) = \sum_{n=1}^{K} C_n S(substrate)_n / C$$

(N and $S(substrate)_n$ mean as described above. C_n denotes a thickness of the layer positioned in number n from the bottom of the unitary laminate after firing the unitary laminate. C denotes a thickness of a substrate after firing the unitary laminate.) $T_{70}(substrate)$ can be calculated by the following formula 9):

9)
$$T_{70}(substrate) = \sum_{n=1}^{N} C_n' T_{70}(substrate)_n/C$$

(N, T70(substrate),, Cn, and C mean as described above.) When a green sheet is constituted of a plurality of layers, S(sheet) and T70(sheet) can be calculated in the same manner.

Therefore, according to the method of the present invention, influence of a mid-sintering temperature and a shrinkage rate of a green substrate to a green sheet with a change by a distance from the green sheet is adjusted. That is, a green substrate is constituted of a plurality of layers each having an independent mid-sintering temperature and an independent shrinkage rate, and the values are adjusted. Accordingly, a disphragm portion can have a protrudent shape toward the side opposite to the window portion formed in a substrate, and a waviness of a diaphragm structure and/or a warpage of a ceramic plate including diaphragm structures can be advantageously minimized.

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Specifically, in a substrate 7 after firing the unitary laminate shown in Fig. 4, differences in average sintering temperature and in average shrinkage rate are calculated by formulae 4) and 5) as follows:

Difference in average sintering temperature
$$= T_1 \times ((1/2)X^2)_{-350}^{-250} + T_2 \times ((1/2)X^2)_{-350}^{-150} + T_3 \times ((1/2)X^2)_{-50}^{-50} + T_4 \times ((1/2)X^2)_{-360}^{-50} + T_5 \times ((1/2)X^2)_{50}^{250} + T_6 \times ((1/2)X^2)_{250}^{250}$$

$$= (-60000T_1 - 40000T_2 - 20000T_3 + 0T_4 + 60000T_5 + 60000T_6)/2$$

Difference in average shrinkage rate $= S_i \times [(1/2)X^2]_{-50}^{-50} + S_2 \times [(1/2)X^2]_{-250}^{-50} + S_3 \times [(1/2)X^2]_{-60}^{-50} + S_4 \times [(1/2)X^2]_{-50}^{50} + S_4 \times [(1/2)X^2]_{50}^{50} + S_4 \times [(1/2)X^2]_{50}^{50} = (-60000S_4 - 40000S_4 - 20000S_4 + 60400S_4 + 60000S_4)/2$

Incidentally, $T_1 - T_6$ and $S_1 - S_6$ denote a mid-sintering temperature and a shrinkage rate, respectively, of the layer positioned in number n place. The fifth layer has a thickness of 200 μ m after firing. The other layer has a thickness of 200 μ m after firing.

When layers constituting a green substrate are connected to one another, a connecting layer is formed in each of the gaps between the layers. In such a case, the connecting layer is treated as a substrate in the aforementioned calculation.

calculation.

In the present invention, a mid-sintering temperature (°C) of a green substrate in a portion below a neutral line of the substrate after firing the unitary laminate is preferably higher than that of a green sheet in view of enhancing a threshold the substrate after firing the unitary laminate is preferably higher than that of a green sheet in view of enhancing a torming stability of a protrudent shape.

The mid-sintering temperature (°C) of a green substrate below the neutral line after firing is expressed by the following formula 6):

6)
$$\sum_{n=1}^{K} [A_n \times T_{70}(substrate)_n]/A$$

(M denotes the number of layers positioned below a neutral line among the layers constituting a substrate after firing a unitary laminate. A, denotes a thickness of the layer positioned in number n place from the lowest layer among the layers constituting a substrate after firing the unitary laminate. However, regarding the layer positioned in number M from the lowest layer, A_n denotes a thickness from the lower surface of the layer to the neutral line. T₇₀(substrate)_A means as described above. A denotes a distance from the lower surface of the lowest layer of a substrate to the neutral line after firing the unitary laminate.)) A mid-sintering temperature (°C) of a green sheet is expressed by the following

formula 7):

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7) $\sum_{n=0}^{L} [B_n \times T_{70}(\text{sheet})_n] / B$

(L denotes the number of layers constituting a green sheet. T_{Di}csheetl), denotes a mid-sintering temperature (°C) of a layer positioned in number n place from the lowest layer among the layers constituting a green sheet when the unitary laminate is positioned so that the green sheet is disposed upside of the substrate. B_n denote a thickness of the layer positioned in number n place from the lowest layer among the layers constituting a diaphragm plate. B denote a thickness of a diaphragm plate. B

In the present invention, a ceramic diaphragm structure is produced by using a green substrate and a green sheet satisfying the above condition. Specifically, it is produced as follows:

In the beginning a green substrate and a green sheet are molded. As a material of a green substrate and a green sheet, there may be used multie beryllia, spinel, titania, aluminum nitride, silicon nitride, stabilized zirconia, a partially stabilized zirconia alumina or a mixture thereof. Alternatively, there may be used a raw material which becomes one of the alforementioned material after firing.

Particularly, a material for a green sheet is preferably a partially stabilized zirconia, stabilized zirconia, alumina, a mixture thereol, or a raw material which becomes one of these materials after firing. More preferably, as the present inventor disclosed in Japanese Patent Laid Open 5-270912, there is used a material having as a main component a partially stabilized zirconia consisting mainly of tetragonal crystals or a mixed crystals consisting of at least two kinds selected from tetragonal crystals. cubic crystals, monocinic crystals, subject of from tetragonal crystals. cubic crystals, monocinic crystals, subject of from tetragonal crystals.

A material for the green substrate is preferably the same as that of the green sheet in view of ensuring reliability and unitary forming of the green substrate and the green sheet. Alternatively, there may be used a ceramic material such as a class-ceramic or corderite.

Incidentally, the green sheet is desirably formed with using a partially stabilized zirconia, stabilized zirconia, alumina, a material containing a mixture thereof as a main component, or a raw material which becomes one of these materials after firing the material having a form of powder having an average particle diameter of 0.05 - 1.0 µm in view of mechanical strength of a dephragm portion.

A diaphragm plate of a ceramic diaphragm structure is preferably 30 μm or less, more preferably 3 - 20 μm. The diaphragm plate has a relative density (bulk density / theoretical density) of preferably 90% or more, more preferably 95% or more, furthermore preferably 99% or more in view of strength. Yound's modulus, or the like

A thickness of a substrate is not particularly limited, and it is suitably determined depending on its use of a diaphragm structure. However, a total thickness of a substrate is preferably 50 µm or more in order to increase an effect of the present invention.

A green substrate and a green sheet can be obtained by preparing a slurry or a paste obtained by adding a binder, a plasticizer, a dispersant, a sintering aid, an organic solvent, etc., to the aforementioned material; motiding constituent members by a conventionally known method such as a doctor blading, a calendering method, and a reverse roll coater method; subjecting the constituent members to cutting, trimming, punching, or the like as necessary; and plining up the constituent members so as to dive a predetermined shape and a predeterment thickness.

Then, a green sheet is superposed on a green substrate so as to prepare a unitary laminate. The green sheet is superposed on the green substrate so as to cover a window portion formed in the green sheet. The unitary laminate can be obtained by heat-pressing or the like.

Finally, the unitary laminate is subjected to firing so as to obtain a ceramic diaphragm structure which diaphragm portion has a protrudent shape toward the side opposite to the window portion formed in a substrate. Incidentally, a firing temperature is preferably 1200 - 1700°C, more preferably 1300 - 1600°C.

[Example]

The present invention is described in more detail on the basis of Examples. However, the present invention is by no means limited to the Examples.

(Example 1)

By a method of the present invention, there is produced a ceramic diaphragm structure having a substrate having two layers so as to satisfy the aforementioned formulae 1), 2), 3); and 4).

To 100 parts by weight of a partially stabilized zirconia powder (containing 0.1 - 0.5 % of alumina) having an average

particle diameter of 0.4 · 1.0 µm were added 7.6 parts by weight of poly(vinyl butyral) as a binder, 3.8 parts by weight of diocityl phthalate as a plasticizer, 80 parts by weight of mixture of toluene and 2-propanol in the ratio of 1:1 (by volume) as a solvent, and 0 · 2.0 parts by weight of sorbitan fattly acid ester as a dispersant as necessary. They were winked together by a ball mill for 5 · 50 hours so as to obtain a slurry. The slurry was deaired and a viscosity was adjusted so that the slurry for the green sheet has a viscosity of 2000 cps and that the slurry for the green substrate has a viscosity of 2000 cps.

The alorementioned sturry was moded so as to have a predetermined shape by a doctor blading to obtain each layer constituting a green substrate and by a reverse roll coater method to obtain a green sheet.

incidentally, a shrinkage rate becomes smaller when a time for mixing a material by a ball mill is longer, or when an amount of a dispersant is larger. A mid-sintering temperature becomes lower when a time for mixing in a ball mill is longer or when an amount of alumina is larger. By controlling these factors, a shrinkage rate of a green substrate is adjusted to be 20.76%, and a shrinkage rate of a green sheet is adjusted to be 21.50%.

A mid-sintering temperature of the first layer (when a ceramic diaphragm structure is disposed so that a diaphragm plate is placed in the upper side, a layer positioned in number in from the bottom is referred to as in this layer. Hereinbelow, the same manner,) of a green substrate was adjusted to be 1310°C, a mid-sintering temperature of the second layer was adjusted to be 1320°C, and a mid-sintering temperature of the second layer.

The aforementioned diaphragm structures were measured for a presence of protrudent shape in a diaphragm. Each of the diaphragm structures were measured for amount of a waviness, and a ceramic plate including the diaphragm structures were measured for amounts of a warpage. The results are shown in Table 1. Additionally, Table 1 phragm structures were measured for amounts of a warpage. The results are shown in Table 1 and distinction and a more selected and a selected and a selected and a more selected and a more selected and a selected

(Fxamples 2 - 8)

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In each of Examples 2 - 8, a ceramic plate having four ceramic diaphragm structures which satisfies the aforementioned formulae 1), 2), 3), and at least one of the formulae 4) and 5) and which consists of two layers was produced in the same manner as in Example 1 except that a mid-sintering temperature and a shrinkage rate of each of the layers constituting a green substrate were changed. In each of Examples 4 and 8, a mid-sintering temperature and a shrinkage rate of a green sheet were 1262°C and 21.38%, respectively.

The aforementioned diaphragm structures were measured for a protrudent shape of a diaphragm portion, a wavtion of the diaphragm structures and/or a warpage of a ceramic plate including the diaphragm structures. The results are shown in Table 1. In Table 1 are also shown values such as a difference in average sintering temperature of a green substrate, the values being calculated on the basis of a mid-sintering temperature and a shrinkage rate of each of layers constituting the green substrate and the aforementioned formulae.

Presence of Protrudent shape present resent present present present present present resent farpage and/or raviness ll gras Lleas Hell lleas Small 1184 11688 E temperature below neutral line (°C) Mid-sintering 1360 1322 322 310 1212 1340 33 310 .5 rate Difference i shrinkage r average 2 • 0 š 8 Š 2 average sintering Difference In terperature 0 0 0 Š Š % 2 S(Substrate) 22.78 20.19 20.45 20. BM 20.54 ક 20.76 20.36 20.47 S(Substrate). 20.00 22.48 18.00 3.4 20.45 20.70 2 2 8 2 3 8 8 ន់ន Tra(Substrate) 322 1325 38 1360 355 385 320 291 T..(Substrate). 325 1322 1310 1360 1330 1310 272 370 Thickness (µm) 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 First layer Second layer a layer

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Example

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(Comparative Examples 1 - 6)

A ceramic plate having diaphragm structures which satisfies the aforementioned formulae 1), 2), and 3) or the formulae 2) and 3) and which satisfies none of the formulae 4) and 5) or the formulae 1), 4) and 5) was produced in the same manner as in Example 1 except that a mid-sintering temperature and a shrinkage-rate of each of the layers constituting a green substrate are different from those of Example 1. Incidentally, a mid-sintering temperature and a shrinkage rate of a green sheet are 1272°C and 21.50%, respectively, which are the same as those of Example 1.

The aforementioned diaphragm structures were measured for a protrudent shape of a diaphragm portion, a wavtises of the diaphragm structures and/or a warpage of a ceramic plate including the diaphragm structures. The results
are shown in Table 2. In Table 2 are also shown values such as a difference in average sintering temperature of a
green substrate, the values being calculated on the basis of a mid-attering temperature and a shrinkage rate of each
of layers constituting the green substrate and the aforementioned formulae.

Presence of Protrudent shape	absent	present	present	present	present	present
Farpage and/or raviness	lless	sedius	large	large	large	very large
bifference in Hid-cintering average tesperature belov shrinkage rate newtral line (°C)	1272	1310	1330	1330	1322	1322
Difference in average shrinkage rate	6	•		6	0	0
Difference in average sintering teeperature			•	0	0	6
S(Substrate) (X)	20.00	20.72	20.79	20.76	20.97	20.84
S(Substrate).	20.00	20. 72	20.79 20.79	20.75	20.97	20.97
Tv.(Substrate)	1272	1310	1330	1320	1323	1322
hickness [7(Sabatrate), [7.(Sabatrate)] S(Sabatrate), S(Sabatrate) (ps) (C) (C) (C) (C) (C) (C)	1272	1310	1330	1330	1322	7261
Thickness (#B)	001	961	8 8	80 80	901	001
n layer	First layer Second layer	First layer Second layer	First layer Second layer	First layer Second layer	First layer Second layer	6 First layer Second layer
	-	2	60	-	20	9

Table 2

(Example 9)

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A ceramic plate having diaphragm structures which substrate consists of five layers was produced so as to satisfy the formulae 1), 2), 3), 4), and 5).

With 100 weight parts of an alumina powder having an average diameter ranging from 0.2 to 0.8 µm were mixed With 100 weight parts of an alumina powder having an average diameter ranging from 0.2 to 0.8 µm were mixed 11 weight parts of poly(viny) buryral) resin as a binder, 5.5 weight parts of diocryl phthalate as a plastice; 11 weight parts of a mixture of toluene and 2-propanol in the ratio of 1: 1 by volume as a solvent, and 0 - 3.0 weight parts of sorbitan latty acid ester as a dispersant as necessary by a ball mill for 5-50 hours so as to prepare a slurry. The sturry was deaired, and viscosity of the slurry was adjusted to be 2000 cps for a green sheet and 20000 cps for a green substrate. Each of the layers constituting a green substrate and a green sheet was formed in the same manner as in

Examilier 1.

By controlling the same factor as Example 1, a shrinkage rate and a mid-sintering temperature of the green sheet were adjusted to be 21,40% and 1270°C, respectively. On the other hand, shrinkage rates of the green substrate were adjusted to be 20.50%, 20.89%, 20.39%, and 20.79% from the first layer, and mid-eintering temperatures of the green substrate were adjusted to be 1310°C, 1340°C, 1350°C, 1360°C, and 1330°C.

The alorementioned layers were piled up so as to obtain the green substrate consisting of five layers. Then, the green sheet was superposed on the green substrate so as to obtain a unitary laminate, which was subjected to a heat green sheet was superposed on the green substrate so as to obtain a unitary laminate was fired at 1550°C for 3 hours pressing treatment at 100°C under 200 kg/cm² for one minute. The unitary laminate was fired at 1550°C for 3 hours os as to obtain a ceramic plate 15 having flow disphragm structures 3 having three windows 8 as shown in Fig. 6. A shape of each of the window portion 8, i.e., disphragm portion 1 has a rectangular shape having dimensions of 0.8 x shape of each of the window portion 8, i.e., disphragm portion 1 has a rectangular shape having dimensions of 0.8 x shape of each of the window shape of the substrate 2 had the similar shape as the fifth layer. The first and the third layers fourth and the second layers of the substrate 2 had the similar shape as the fifth layer. The first and the third layers were provided with throughholes 10 each having a diameter of 0.2 mm after firing and being connected with each of the window portions 8. The first, second, third, fourth, and fifth layers of the substrate 2 had a thickness of 200 µm, 250 µm, and 100 µm, respectively. A thickness of a diaphragm plate 12 had a thickness of 20 µm.

The aforementioned diaphragm structures were measured for a protrudent shape of a diaphragm portion, a waviness of the diaphragm structures and/or a warpage of a ceramic plate including the diaphragm structures. The results are shown in Table 3. In Table 3 are also shown values such as differences in average sintering temperature and average shrinkage rate of a green substrate and a mid-sintering temperature and a shrinkage rate of the whole green substrate and a mid-sintering temperature of a portion below a neutral line of a green substrate, the values being calculated on the basis of the aforementioned formulae.

(Example 10)

A ceramic plate having diaphragm structures which substrate consists of five layers was produced so as to satisfy the formulae 1), 2), 3), and 4) in the same manner as in Example 9 except that each of the layers constituting a green substrate had a different mid-sintering temperature and a different shrinkage rate from those of Example 9, incidentally, the green sheet had a mid-sintering temperature of 1280°C and a shrinkage rate of 21.30%.

The aforementioned diaphragm structures were measured for a protrudent shape of a diaphragm portion, a waviness of the diaphragm structures and/or a warpage of a ceramic substrate including the diaphragm structures. The results are shown in Table 3. In Table 3 are also shown values such as a difference in average sintering temperature of a green substrate, the values being calculated on the basis of a mid-sintering temperature and a shrinkage rate of each of layers constituting the green substrate and the aforementioned formulae.

(Comparative Example 7)

A ceramic plate having diaphragm structures which satisfies the formulae 1), 2), and 3), and which does not satisfy 4) was produced in the same manner as in Example 9 except that a mid-shtering temperature and a shrinkage rate of each of layers constituting a green substrate were different from those of Example 9. Incidentally, a mid-shtering temperature and a shrinkage rate of a green sheet used for a diaphragm plate were 1270°C and 21.40%, respectively, as in Example 9.

The aforementioned diaphragm structures were measured for a protrudent shape of a diaphragm portion, a waviness of the diaphragm structures and/or a warpage of a ceramic plate including the diaphragm structures. The results are shown in Table 3. In Table 3 are also shown values such as a difference in average sintering temperature of a green substrate, the values being calculated on the basis of a mid-sintering temperature and a shrinkage rate of each of layers constituting the green substrate and the aforementioned formulae.

Table 3

	-										,
n layer Th	F	hickness (µm)		T(Substrate) (*C)	S(Substrate).	S(Substrate)	Difference in average sintering tesperature	Difference in average shrinkage rate	Difference in Rid-sintering average temperature below shrinkage rate meutral line (°C)	farpage and/or raviness	Presence of Protrudent shape
First laws		200	1310	1330	20.50	20.59	2	×	1323	spall	present
Second Javer		23	1340		20.63						
Third layer		901	1330		20.59						
Fourth layer		55	1360		20.38						
Fifth layer		100	1330		20.79						
First larer		200	1330	1336	20.72	20.78	8^	ş.	1326	Ilan	present
Second layer		220	1320		20.91						
Third layer		8	1345		20.78						
Fourth layer		25	1370		20.38						
Fifth layer		001	1360		20.79						
First laver	$\neg \neg$	8	1360	1325	20.72	20.53	0	Ŷ	1339	large	present
Second layer		220	1310		20.30						
Third layer		100	1300		20.53						
Fourth layer		25	1315		20.38						
Fifth layer		801	1320	-	20. 79						
		_		_							

In each Example, all the diaphragmportions had a protrudent shape, and there was only a small degree of waviness caused in the diaphragm structures and/or a warpage of a ceramic plate including the diaphragm structures. On the other hand, in each Comparative Example, some of the diaphragm portions did not have a protrudent shape. Concerning the diaphragm portions which had a protrudent shape in Comparative Examples, the diaphragm structures or a ceramic plate including the diaphragm structures had a large degree of warpage or waviness.

In a method of the present invention, mid-sintering temperatures and shrinkage rates of a green substrate and a green sheet are controlled so as to satisfy predetermined formulae. Accordingly, it makes possible an adjustment in consideration of a change of influence of a mid-sintering temperature and a shrinkage rate of a green substrate on a green sheet, the adjustment including a change of influence depending on a distance from the green sheet. As a result, a diaphragm portion has a protrudent shape toward the side opposite to the window portion of the substrate, and a waviness of a diaphragm structure and/or a warpage of a ceramic plate including diaphragm structures after firing can be advantageously minimized. Accordingly, when a diaphragm structure is used as a sensor, a variance of detection preciseness can be prevented. When a diaphragm structure is used as a piezoelectric/electrostrictive actuator, a deterioration or variance of displacement can be avoided.

Claims

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A method for producing a ceramic diaphragm structure comprising:

superposing a thin ceramic green sheet having at least one layer on a ceramic green substrate having at least one window portion and at least one layer so as to cover the window portion to obtain a unitary laminate; and firing the unitary laminate so that a disphragm portion has a protrusion toward a side opposite to the window portion;

wherein the ceramic green substrate and the ceramic green sheet satisfy the formulae:

1) S(substrate) - S(sheet)
$$\geq$$
 -0.08 {T₇₀(substrate) - T₇₀(sheet)} - 1

2)
$$0 \le T_{70}$$
(substrate) - T_{70} (sheet) ≤ 300

and

3) S(substrate) - S(sheet) ≤ 20

(S(substrate), and S(sheet) denote shrinkage rates (%) of the ceramic green substrate and the ceramic green sheet, respectively. T_{70} (substrate) and T_{70} (sheet) denote mid-sintering temperatures (°C) of the ceramic green substrate and the ceramic green sheet, respectively) and an average sintering temperature difference, shown by the formula

4)
$$\sum_{n=1}^{N} T_{70} (\text{substrate})_n \int_{tn}^{tn-1} \times dx$$

(N denotes the number of layer constituting the ceramic green substrate. T₇₀(substrate)_n denotes a mid-sintering temperature (°C) of a layer positioned in number n place from the bottom of the laminate in the ceramic green substrate having the ceramic green sheet thereon. 1, and 1_{n+1} denote distances from a lower and an upper surfaces, respectively, of the layer positioned in numbers n place to a neutral line of the substrate after firing the unitary respectively, or the layer positioned in numbers of place to a neutral line of the substrate after firing the unitary laminate, with putting - for a surface under the neutral line and + for a surface over the neutral line.) of the ceramic green substrate is larger than 0.

2. A method for producing a ceramic diaphragm structure, comprising:

superposing a thin ceramic green sheet having at least one layer on a ceramic green substrate having at least

one window portion and at least one layer so as to cover the window portion to obtain a unitary laminate; and firing the unitary laminate so that a diaphragm portion has a protrusion toward a side opposite to the window portion:

wherein the ceramic green substrate and the ceramic green sheet satisfy the formulae:

2)
$$0 \le T_{70}(\text{substrate}) - T_{70}(\text{sheet}) \le 300$$

and

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S(substrate) - S(sheet) ≤ 20

(S(substrate), and S(sheet) denote shrinkage rates (%) of the ceramic green substrate and the ceramic green sheet, respectively. T₇₀(substrate) and T₇₀(sheet) denote mid-sintering temperatures (°C) of the ceramic green substrate and the ceramic green sheet, respectively.) and an average shrinkage-rate difference, shown by the formula:

5)
$$\sum_{n=0}^{\infty} T_{70}(substrate)_n \int_{tn}^{tn+1} \times dx$$

(N denotes the number of layer constituting the ceramic green substrate. S(substrate), denotes a shrinkage rate (%) of a layer positioned in number n place from the bottom of the laminate in the ceramic green substrate having the ceramic green sheet thereon. In and In., denote distances from a lower and an upper surfaces, pespectively, of the layer positioned in numbers n place to a neutral line of the substrate after firing the unitary laminate, with putting-for a surface under the neutral line and + for a surface over the neutral line.) of the ceramic green substrate is larroer than 0.

 A method for producing a ceramic diaphragm structure according to claim 1 or 2, wherein a mid-sintering temperature (°C) obtained by formula 6)

6)
$$\frac{H}{h_1}[A_n \times T_{70}(substrate)_n]/A$$

(M denotes the number of layers positioned under the neutral line among the layers constituting a ceramic substrate after firing the unitary laminate. A_n denotes a thickness of a layer positioned in number n place from the bottom of the substrate after firing the unitary laminate. However, concerning the layer positioned in number M, A_n denotes a distance from the lower surface of the layer to the neutral line. T₇₀(Substrate), denotes a mid-sintering temperature (C) of a layer positioned in number n place from the bottom of the laminate in the carmic green substrate having the ceramic green sheet thereon. A denotes a distance from the lower surface of the lowest layer to the neutral line of the substrate after firing the unitary laminate) is larger than a mid-sintering temperature (°C) of the ceramic green sheet, the mid-sintering temperature (°C) being obtained by the formula 7)

7)
$$\Sigma[B_n \times T_{70}(\text{sheet})_n/B]$$

(L denotes the number of layers constituting the ceramic green sheet. T_{70} (sheet), denotes a mid-sintering temperature (°C) of a layer positioned in number n place from the bottom of the laminate constituting the ceramic green sheet when the ceramic green sheet is positioned in the upside of the ceramic green substrate. B, denotes

- a thickness of a layer positioned in number n place from the bottom of the layers constituting a diaphragm plate after firing the unitary laminate. B denotes a thickness of the diaphragm plate.)
- 4. A method for producing a ceramic diaphragm structure according to any one of claims 1, 2, and 3, wherein the ceramic green sheet is made of a partially stabilized zirconia, completely stabilized zirconia, alumina or a mixture thereof, or a raw material which become one of the aforementioned materials after being fired, any of them having an average particle claimeter of 0.05 1.0 µm.

FIG. 1

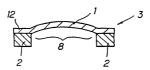
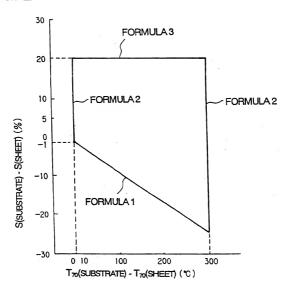


FIG. 2



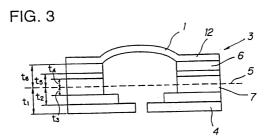


FIG. 4

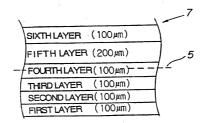


FIG. 5

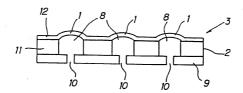
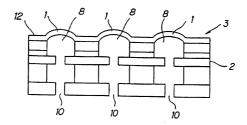
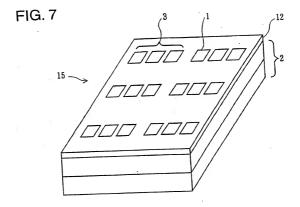


FIG. 6







European Patent

EUROPEAN SEARCH REPORT

Application Number

	DOCUMENTS CONSIDER Cdation of document with indica		Relevant	CLASSIFICATION OF THE
ategory	Cdation of document with indica of relevant passages	ation, where appropriate,	to claim	APPLICATION (InLCL6)
4	EP 0 713 255 A (NGK I 1996 * the whole document		1-4	H01L41/09 C04B35/486 C04B35/111
A	EP 0 671 772 A (NGK I September 1995 * the whole document		1-4	
	*		*=	
				TECHNICAL FIELDS SEARCHED (INL.CLS) HOLL CO4B
	The present search report has	been drawn up for all claims Dute of completion of the search		- Everyor
8	Place of search THE HAGUE	26 September 1	- 1	Pelsers, L
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